



SamHop Microelectronics Corp.



STS 4501

Oct. 12,2007

## P-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
V <sub>DSS</sub>	I <sub>D</sub>	R <sub>DSON</sub> (mΩ) Max
-40V	-3.5A	65 @ V <sub>GS</sub> = -10V
		85 @ V <sub>GS</sub> = -4.5V

### FEATURES

- Super high dense cell design for low R<sub>DSON</sub>.
- Rugged and reliable.
- SOT-23 Package.



### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	- 40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous @ T <sub>J</sub> =25°C -Pulsed <sup>b</sup>	I <sub>D</sub>	-3.5	A
	I <sub>DM</sub>	- 14	A
Drain-Source Diode Forward Current	I <sub>S</sub>	-1.25	A
Maximum Power Dissipation <sup>a</sup>	P <sub>D</sub>	1.25	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C

### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient <sup>a</sup>	R <sub>θJA</sub>	100	°C/W
--	------------------	-----	------

# STS4501

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ C$  unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ <sup>c</sup>	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-40			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -32V, V_{GS} = 0V$			-1	$\mu A$
Gate-Body Leakage	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	nA
<b>ON CHARACTERISTICS <sup>a</sup></b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-1.6	-3	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS} = -10V, I_D = -3.5A$		54	65	m ohm
		$V_{GS} = -4.5V, I_D = -2A$		70	85	m ohm
On-State Drain Current	$I_{D(ON)}$	$V_{DS} = -5V, V_{GS} = -10V$	-20			A
Forward Transconductance	$g_F$	$V_{DS} = -10V, I_D = 3.5A$		8.7		S
<b>DYNAMIC CHARACTERISTICS <sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = -25V, V_{GS} = 0V$ $f = 1.0MHz$		660		pF
Output Capacitance	$C_{oss}$			100		pF
Reverse Transfer Capacitance	$C_{rss}$			60		pF
<b>SWITCHING CHARACTERISTICS <sup>b</sup></b>						
Turn-On Delay Time	$t_{D(ON)}$	$V_{DD} = -20V$ $I_D = -1A$ $V_{GS} = -10V$ $R_{GEN} = 3.3 \text{ ohm}$		10.5		ns
Rise Time	$t_r$			11		ns
Turn-Off Delay Time	$t_{D(OFF)}$			72		ns
Fall Time	$t_f$			22		ns
Total Gate Charge	$Q_g$	$V_{DS} = -28V, I_D = -3.5A, V_{GS} = -10V$		13		nC
		$V_{DS} = -28V, I_D = -3.5A, V_{GS} = -4.5V$		6.5		nC
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -28V, I_D = -3.5A$ $V_{GS} = -10V$		1.4		nC
Gate-Drain Charge	$Q_{gd}$			3.8		nC

# STS4501

ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS <sup>b</sup>						
Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0\text{V}$ , $I_S = -1.25\text{A}$		-0.75	-1.2	V

## Notes

- a. Surface Mounted on FR4 Board,  $t \leq 10\text{sec}$ .
- b. Pulse Test Pulse Width  $\leq 300\text{us}$ , Duty Cycle  $\leq 2\%$ .
- c. Guaranteed by design, not subject to production testing.

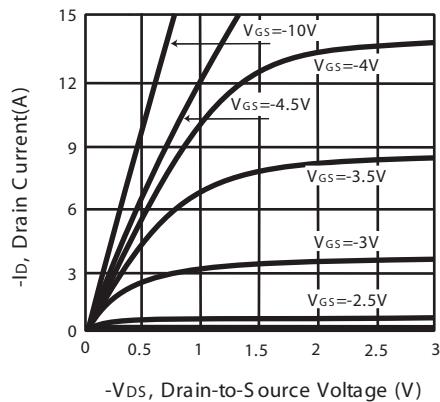


Figure 1. Output Characteristics

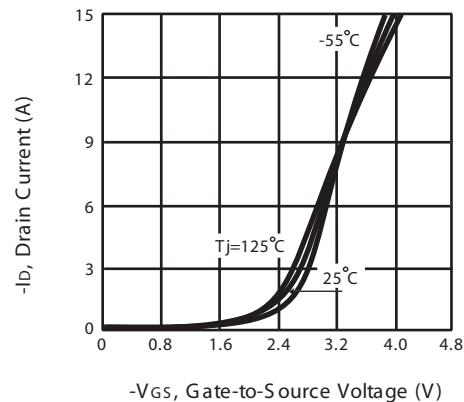


Figure 2. Transfer Characteristics

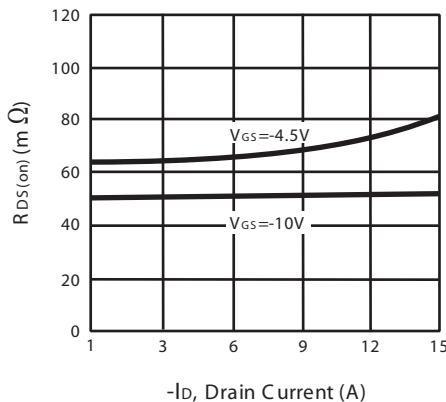


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

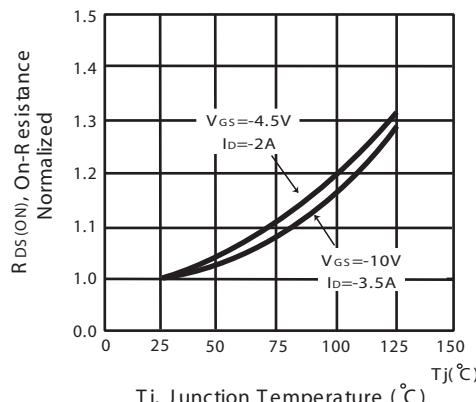
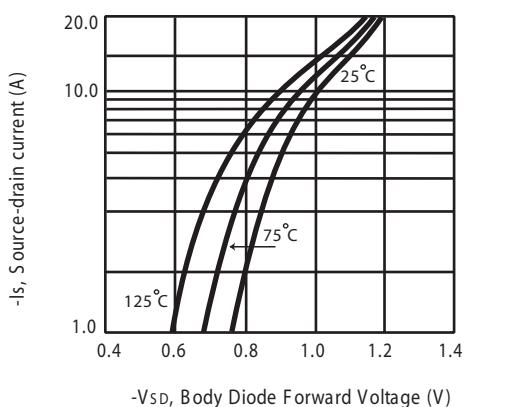
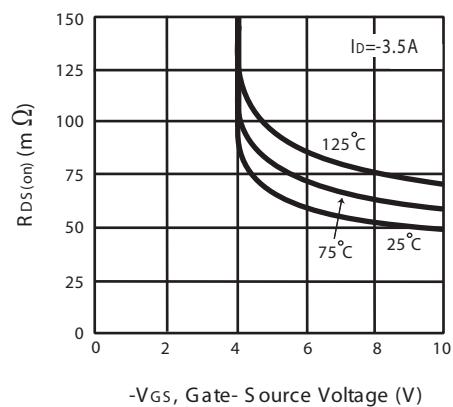
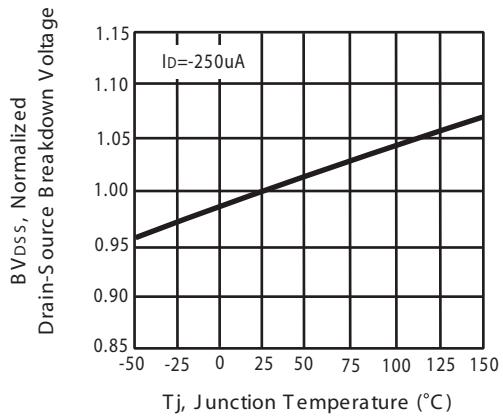
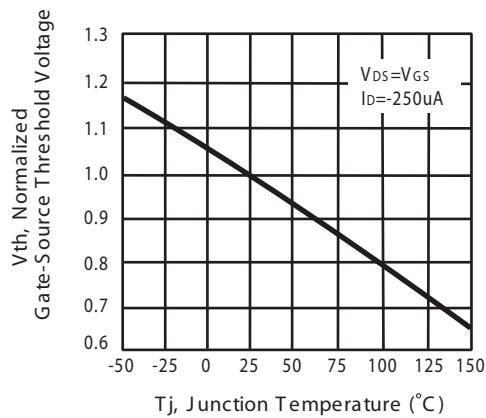


Figure 4. On-Resistance Variation with Drain Current and Temperature

# STS4501



# STS4501

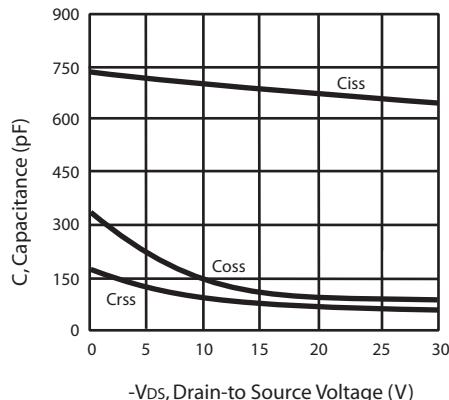


Figure 10. Capacitance

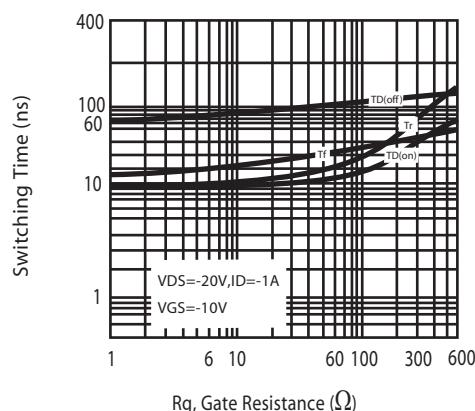
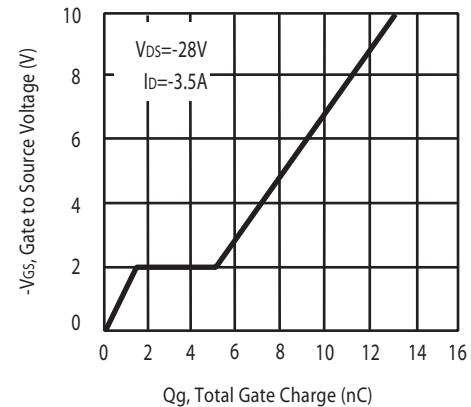


Figure 12. switching characteristics

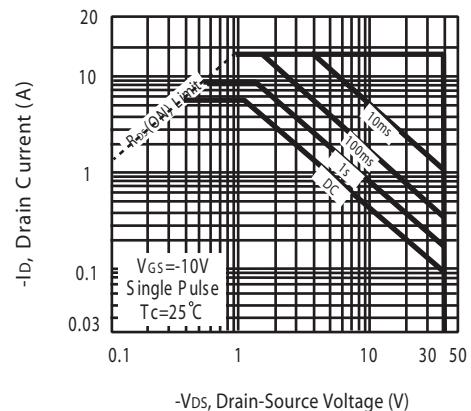
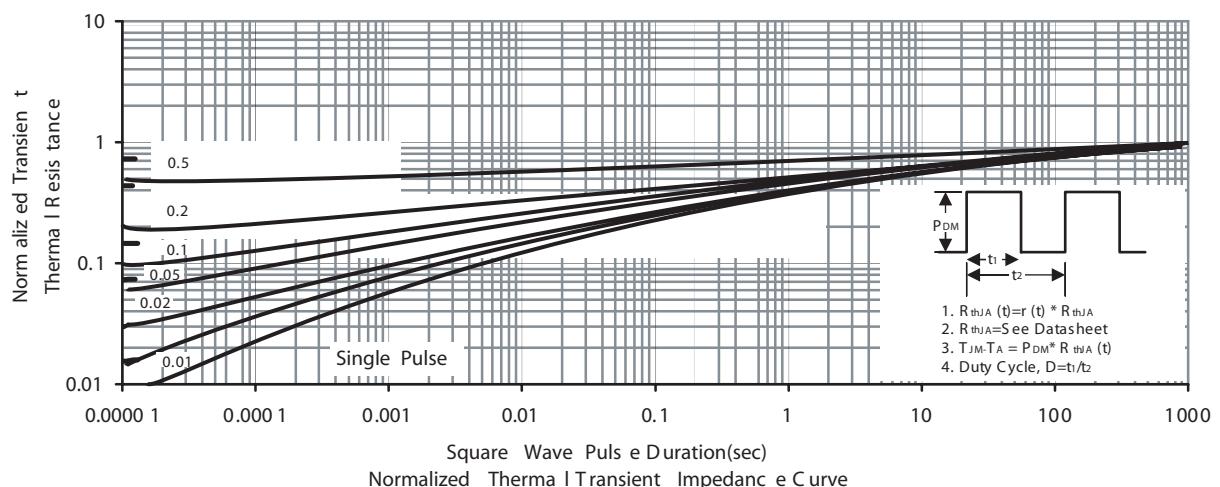


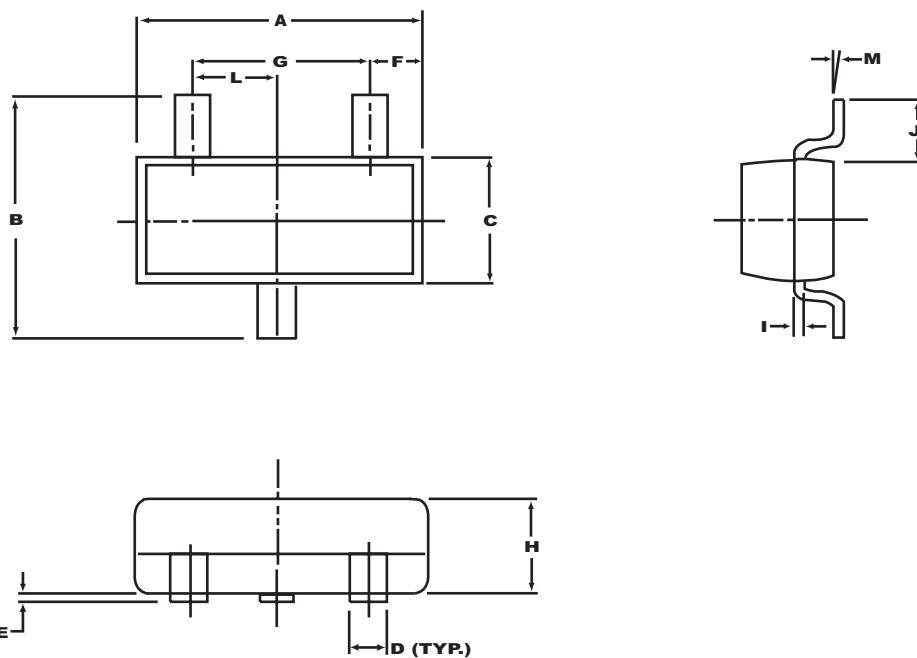
Figure 13. Maximum Safe Operating Area



# STS4501

## PACKAGE OUTLINE DIMENSIONS

SOT-23

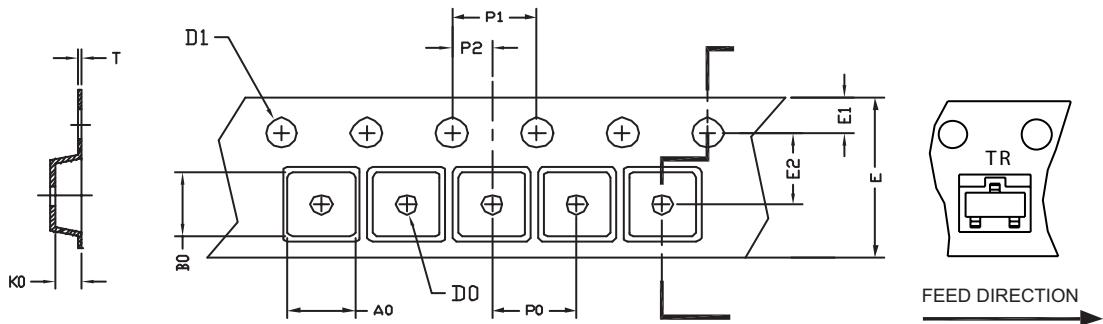


SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.106	0.122
B	2.40	2.80	0.094	0.110
C	1.40	1.60	0.055	0.063
D	0.35	0.50	0.014	0.020
E	0	0.10	0	0.004
F	0.45	0.55	0.018	0.022
G	1.90 REF.		0.075 REF.	
H	1.00	1.30	0.039	0.051
I	0.10	0.20	0.004	0.008
J	0.40	-	0.016	-
L	0.45	1.15	0.033	0.045
M	0°	10°	0°	10°

# STS4501

## SOT-23 Tape and Reel Data

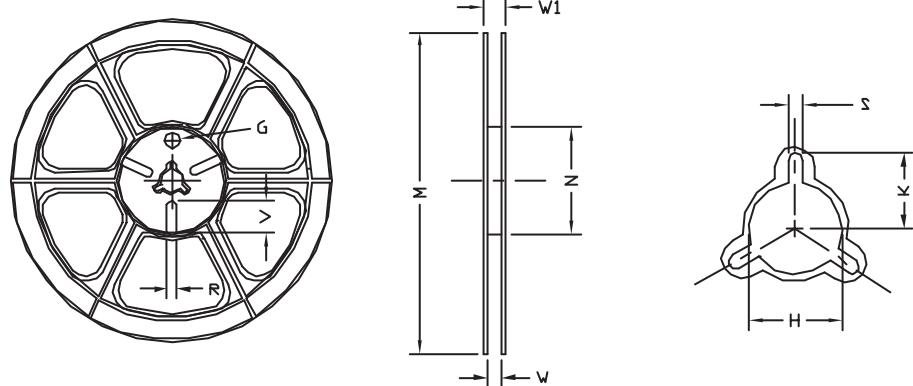
### SOT-23 Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
SOT-23	3.20 ±0.10	3.00 ±0.10	1.33 ±0.10	§ 1.00 +0.25	§ 1.50 +0.10	8.00 +0.30 -0.10	1.75 ±0.10	3.50 ±0.05	4.00 ±0.10	4.00 ±0.10	2.00 ±0.05	0.20 ±0.02

### SOT-23 Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
8mm	§ 178	§ 178 ±1	§ 60 ±1	9.00 ±0.5	12.00 ±0.5	§ 13.5 ±0.5	10.5	2.00 ±0.5	§ 10.0	5.00	18.00